


SELECTED ITEM DRAWING

			
Unless otherwise specified DIMENSIONS ARE IN INCHES (MM)	TOLERANCES: .XX +/- 0.010 .XXX +/- 0.005 .XXXX +/- 0.002 ANGLES +/- .5 DEG	Drawing practices per ASME Y14.100	DC to 2010 MHz, SP8T Non-Reflective Switch
			SIZE A

SID000057 **Rev. C**
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1. SCOPE

1.1. Scope

This drawing establishes the requirements for the DC to 2010 MHz, GaAs, MESFET, MMIC, SP8T Non-Reflective Switch, assembled hermetically in the G24 package, to be screened in accordance with MIL-PRF-38535, Class Level S, to the requirements specified in 4.1, 4.2, and 4.3 herein.

1.2. Analog Devices Part Number

<u>Generic Part Number</u>	<u>Screened Part Number</u>
ADH322S	HMC8058G24

2. APPLICABLE DOCUMENTS

2.1. Government Documents

Unless otherwise specified, the following drawings and standards, of the issue in effect on the date of the accepted purchase order, in the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, shall form a part of this drawing to the extent specified herein.

DEPARTMENT OF DEFENSE TEST METHOD STANDARD

MIL-STD-883 Microcircuits

DEPARTMENT OF DEFENSE PERFORMANCE SPECIFICATIONS

MIL-PRF-38535 Integrated Circuits (Microcircuits) Manufacturing, General Specification For

2.2. Non-Government Documents

The following documents, of the issue in effect on the date of the purchase order, form a part of this drawing to the extent specified herein:

Analog Devices Inc.

[ADI Standard Space Products Program](#) – ASD-Lite.

HMC322LP4 / 322 LP4E Data Sheet Commercial Product Datasheet v06.0112 (Reference Only)

3. REQUIREMENTS

3.1. General Requirements

The devices delivered shall comply to this specification.

3.2. Design Construction and Physical Dimensions

The design construction and physical dimensions shall be as defined in Figure 1 herein.

3.3. Traceability

Each delivered device shall be traceable to the wafer lot and wafer number. Inspection lot records shall be maintained to provide traceability to the specific wafer and wafer lot from which the chips originated as well as traceability to package and materials.

3.4. Burn-In and Life Test Circuit

The burn-in and life test circuit and conditions shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test methods 1005 and 1015 per MIL-STD-883.

4. QUALITY ASSURANCE PROVISIONS

4.1. Wafer Lot Acceptance Testing

The wafer lot acceptance testing shall consist of Class Level S inspections per MIL-STD-883 TM 5007.

4.2. Flight Screening Requirements

Flight screening requirements shall be per MIL-STD-883 TM 5004 for Class level S microcircuits.

4.2.1. Electrical Test Requirements

Electrical test requirements are defined in Table I herein.

4.2.2. Electrical Performance Characteristics

Electrical performance characteristics are specified on Table II herein.

4.2.3. Burn-In Delta Requirements

Pre and Post Burn-In Electrical test and delta parameters shall consist of the tests specified in Table III herein.

4.3. Quality Conformance Inspection (QCI)

Group B and Group D tests shall be performed per MIL-STD-883 TM 5005 for Class level S microcircuits.

4.3.1. Post Steady State Life Electrical Test

Post steady state life electrical tests shall consist of the tests specified per Table II tested at room temperature only.

Devices must meet delta parameter requirements in accordance with Table III herein.

5. MIL-PRF-38535 ASD-LITE EXCEPTIONS

The manufacturing flow described in the ADI STANDARD SPACE PRODUCTS PROGRAM is to be considered a part of this specification.

5.1. Wafer Fabrication

Foundry information is available upon request.

5.2. Flight Screening Flow

Reverse Bias Burn-In: Not applicable.

5.3. Group B

Subgroup 2: Resistance to solvents is not applicable.

5.4. Group D

Subgroup 5: Not applicable.

Subgroup 7: Not applicable.

Subgroup 8: Not applicable.

Subgroup 9: Not applicable.

6. PREPARATION FOR DELIVERY

The preparation for delivery, packaging, preservation, ESD protection and handling shall be in accordance with MIL-PRF-38535.

6.1. Part Marking

Devices shall be marked as specified on Figure 1 herein.

6.2. Inspection Data Requirements

The following data shall accompany each shipment.

- a. A Certificate of Conformance (C of C) certifies that the lot(s) meets all requirements of this specification.
- b. Wafer Lot Acceptance data including photos from SEM Inspection defined in 4.1 herein.
- c. Summary of electrical test requirements defined in 4.2 herein.
- d. Summary of QCI results defined in 4.3 herein.
- e. Failure Analysis with photos (If applicable)
- f. A cover sheet indicating the following purchasing information:
 1. Customer purchase order number.
 2. Analog Devices part number.
 3. Part lot identification codes.
 4. Date & quantity shipped.

TABLE I: ELECTRICAL TEST REQUIREMENTS

Test Requirement	Subgroups (in accordance with MIL-PRF-38535, Table III)
Interim Electrical Parameters	1, 4
Final Electrical Parameters	1, 4 <u>1/2</u> /
Group A Electrical Parameters	1, 2, 3, 4, 5, 6
Group B End-Point Electrical Parameters	1, 4 <u>2</u> /
Group D End-Point Electrical Parameters	1, 4

TABLE I Notes:

1/ PDA applies to Table I subgroup 1 and Table III delta parameters.

2/ See Table III for delta parameters

TABLE II: ELECTRICAL PERFORMANCE CHARACTERISTICS (-40 °C, +25 °C AND +85 °C)

Parameter	Test Conditions <u>1/2/3/</u> Unless otherwise specified	Group A Subgroups	Limits		Units
			Min	Max	
Insertion Loss (RFC to RF1 – RF8)		4		3	dB
		5, 6		3.2	dB
Input Return Loss “On-State”		4, 5, 6	7		dB
Output Return Loss “On-State”		4, 5, 6	7		dB
Isolation (RFC to RF1 – RF8)		4, 5, 6	34		dB
Supply Current (IEE)	No Signal at RFC	1		9	mA
		2, 3		10	mA
Control Current	CTLA = CTLB = CTLC = Low State No Signal at RFC	1, 2, 3		50	µA
	CTLA = CTLB = CTLC = High State No Signal at RFC	1, 2, 3		25	µA

TABLE II Notes:

1/ Test limits apply between at -40 °C and +85 °C with VEE = -5V.

2/ Measurements made at RFC = 90 MHz, 570 MHz, 1050 MHz, 1530 MHz, and 2010 MHz unless otherwise noted.

3/ Control voltages (CTLA, CTLB, & CTLC) set to Low State = -3 V and High State = -4.2 V for all testing as required to measure defined parameters.

TABLE III: BURN-IN/LIFE TEST DELTA LIMITS 1/2/3/

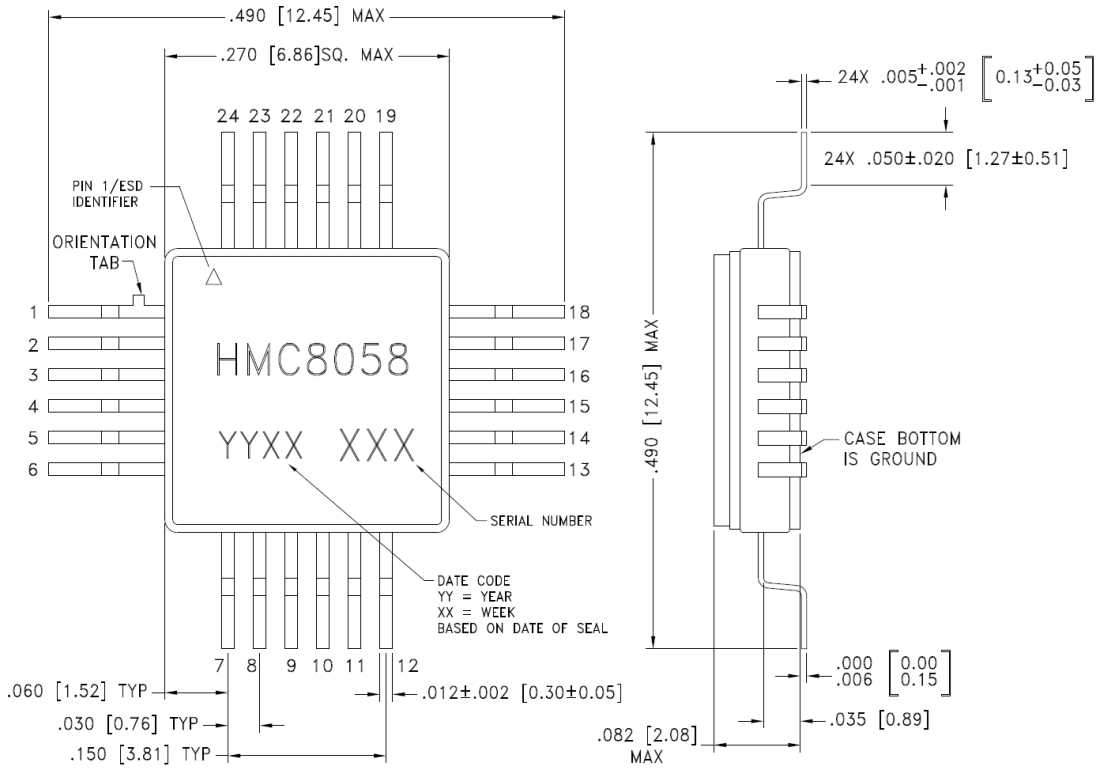
Parameter	Test Conditions	Delta Limits	Units
Insertion Loss (RFC to RF1 – RF8)	Per Table II	± 1	dB

TABLE III Notes:

1/ Delta test is performed at T_A = +25 °C only.

2/ Table II limits will not be exceeded.

3/ Deltas calculated at pre/post 240 hours and post 240 hour / post1000 hours.



NOTES:

1. PACKAGE MATERIAL: ALUMINA LOADED BOROSILICATE GLASS (#7052 CORNING).
2. LEADS, BASE, COVER MATERIAL: KOVAR™.
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 50 MICROINCHES MIN.
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES: ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
6. CHARACTERS TO BE LASER MARKED WITH .018 MIN to .030 MAX HEIGHT REQUIREMENTS. UTILIZE MAXIMUM CHARACTER HEIGHT BASED ON LID DIMENSIONS AND BEST FIT. LOCATE APPROX. AS SHOWN.
7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

PIN #	FUNCTION	PIN #	FUNCTION	PIN #	FUNCTION
1	GND	9	CTLC	17	RF7
2	RF2	10	CTLB	18	GND
3	GND	11	CTLA	19	RF8
4	RF3	12	GND	20	GND
5	GND	13	RF5	21	GND
6	RF4	14	GND	22	RFC
7	GND	15	RF6	23	GND
8	VEE	16	GND	24	RF1

Average Weight: 0.29 grams

Figure 1 – Device Outline for the HMC8058G24

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
HMC8058G24	-40 °C to +85 °C	24-Lead Glass/Metal Hermetic SMT	G24 (FR-24-1)

Revision History

Revision History		
Rev	Description of Change	Date
A	Initial release.	12/03/2024
B	Updated Table II, Section 4.3.1 and Figure 1	08/27/2025
C	Updated Figure 1 notes	01/20/2026